NSN 5961-01-332-5721

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-332-5721 **Inclosure Material:** Metal **Overall Length:** Between 1.510 inches and 1.550 inches **Overall Height:** Between 0.250 inches and 0.300 inches Overall Width: Between 0.980 inches and 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204ae **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 collector to emitter voltage/static/base open and 350.0 collector-to-emitter, with voltage between base and emitter and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 60.00 amperes source cutoff current and 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapons system essential **Test Data Document:** 19623-007637 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-332-5721 Transistor - Page 2 of 2



Fiig:

A110a0